

BIPOLAR ANALOG INTEGRATED CIRCUIT $\mu PC8163TB$

SILICON MMIC 2.0 GHz FREQUENCY UP-CONVERTER FOR CELLULAR TELEPHONE

DESCRIPTION

The μ PC8163TB is a silicon monolithic integrated circuit designed as frequency up-converter for cellular telephone transmitter stage. The μ PC8163TB has improved intermodulation performance and smaller package.

The μ PC8163TB is manufactured using NEC's 20 GHz fr NESATTMIII silicon bipolar process. This process uses silicon nitride passivation film and gold electrodes. These materials can protect chip surface from external pollution and prevent corrosion/migration. Thus, this IC has excellent performance, uniformity and reliability.

FEATURES

Recommended operating frequency : fRFout = 0.8 GHz to 2.0 GHz, fIFin = 50 MHz to 300 MHz

Supply voltage : Vcc = 2.7 to 3.3 V

High-density surface mounting
 Higher IP3
 Minimized carrier leakage
 16-pin super minimold package
 OIP3 = +9.5 dBm @ frageleakage
 Due to double balanced mixer

APPLICATIONS

· Digital cellular phones

ORDERING INFORMATION

Part Number	Package	Supplying Form
μPC8163TB-E3	6-pin super minimold	Embossed tape 8 mm wide. Pin 1, 2, 3 face to tape perforation side. Qty 3 kp/reel

Remark To order evaluation samples, please contact your local NEC sales office.

(Part number for sample order: µPC8163TB)

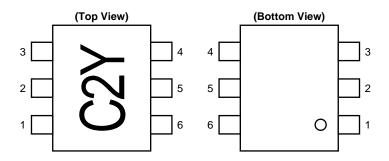
Caution Electro-static sensitive device

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Not all devices/types available in every country. Please check with local NEC representative for availability and additional information.



PIN CONNECTIONS



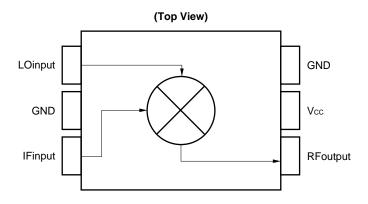
Pin No.	Pin Name
1	IFinput
2	GND
3	LOinput
4	GND
5	Vcc
6	RFoutput

SERIES PRODUCTS (TA = +25°C, Vcc = VRFout = 3.0 V, ZL = Zs = 50 Ω)

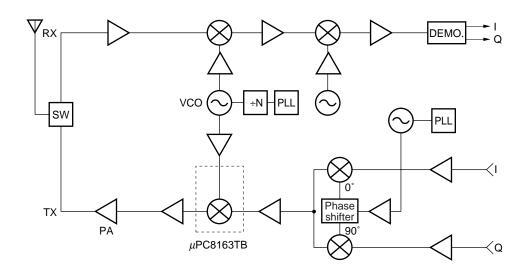
Туре	Part No.	Vcc (V)	Icc (mA)	CG1 (dB)	CG2 (dB)	Po(sat) 1 (dBm)	Po(sat) 2 (dBm)	OIP₃1 (dBm)	OIP ₃ 2 (dBm)
High IP₃	μPC8106TB	2.7 to 5.5	9	9	7	-2	-4	+5.5	+2.0
Low Power Consumption	μPC8109TB	2.7 to 5.5	5	6	4	-5.5	-7.5	+1.5	-1.0
Higher IP ₃	μPC8163TB	2.7 to 3.3	16.5	9	5.5	0.5	-2	+9.5	+6.0

Caution The above table lists the typical performance of each model. See ELECTRICAL CHARACTERISTICS for the test conditions.

BLOCK DIAGRAM (FOR THE µPC8163TB)



SYSTEM APPLICATION EXAMPLES (SCHEMATICS OF IC LOCATION IN THE SYSTEM)



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PIN EXPLANATION

Pin No.	Pin Name	Applied Voltage V	Pin Voltage V ^{Note}	Function and Explanation	Equivalent Circuit
1	lFinput	_	1.2	This pin is IF input to double balanced mixer (DBM). The input is designed as high impedance. The circuit contributes to suppress spurious signal. Also this symmetrical circuit can keep specified performance insensitive to process-condition distribution. For above reason, double balanced mixer is adopted.	© ©
2 4	GND	0	_	GND pin. Ground pattern on the board should be formed as wide as possible. Track Length should be kept as short as possible to minimize ground impedance.	
3	LOinput	_	2.1	Local input pin. Recommendable input level is –10 to 0 dBm.	
5	Vcc	2.7 to 3.3	_	Supply voltage pin.	2
6	RFoutput	Same bias as Vcc through external inductor		This pin is RF output from DBM. This pin is designed as open collector. Due to the high impedance output, this pin should be externally equipped with LC matching circuit to next stage.	

Note Each pin voltage is measured with $Vcc = V_{RFout} = 3.0 V$.



ABSOLUTE MAXIMUM RATINGS

Parameter	Symbol	Test Conditions	Rating	Unit
Supply Voltage	Vcc	T _A = +25°C, Pin 5 and 6	3.6	V
Power Dissipation of Package	PD	Mounted on double-sided copperclad $50 \times 50 \times 1.6$ mm epoxy glass PWB $T_A = +85^{\circ}C$	200	mW
Operating Ambient Temperature	TA		-40 to +85	ပ္
Storage Temperature	T _{stg}		-55 to +150	°C
Maximum Input Power	Pin		+10	dBm

RECOMMENDED OPERATING CONDITIONS

Parameter	Symbol	Test Conditions	MIN.	TYP.	MAX.	Unit
Supply Voltage	Vcc	The same voltage should be applied to pin 5 and 6	2.7	3.0	3.3	V
Operating Ambient Temperature	TA		-40	+25	+85	°C
Local Input Level	PLOin	Zs = 50 Ω (without matching)	-10	- 5	0	dBm
RF Output Frequency	f RFout	With external matching circuit	0.8	-	2.0	GHz
IF Input Frequency	fıFin		50	-	300	MHz

ELECTRICAL CHARACTERISTICS

 $(T_A = +25$ °C, $V_{CC} = V_{RFout} = 3.0 \text{ V}$, $f_{IFin} = 150 \text{ MHz}$, $P_{LOin} = -5 \text{ dBm}$)

1A = 120 0, 100 = 100 0, 11 11 = 100 11 12,1 2011 = 0 0 0111						
Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Circuit Current	Icc	No Signal	11.5	16.5	23	mA
Conversion Gain 1	CG1	frefout = 830 MHz, PlFin = -20 dBm	6	9	12	dB
Conversion Gain 2	CG2	frefout = 1.9 GHz, PiFin = -20 dBm	2.5	5.5	8.5	dB
Maximum RF Output Power 1	Po(sat) 1	frefout = 830 MHz, PiFin = 0 dBm	-1.5	0.5	-	dBm
Maximum RF Output Power 2	Po(sat) 2	freout = 1.9 GHz, PiFin = 0 dBm	-4.5	-2	_	dBm

OTHER CHARACTERISTICS, FOR REFERENCE PURPOSES ONLY

 $(T_A = +25^{\circ}C, V_{CC} = V_{RFout} = 3.0 \text{ V}, P_{LOin} = -5 \text{ dBm})$

Parameter	Symbol	Conditions		Data	Unit
Input Third Order Distortion Intercept	IIP₃ 1	fiFin1 = 150.0 MHz	frefout = 830 MHz	0.5	dBm
Point	IIP ₃ 2	f _{IFin} 2 = 150.4 MHz	frefout = 1.9 GHz	0.5	
Output Third-Order Distortion	OIP ₃ 1	fıFin1 = 150.0 MHz	frefout = 830 MHz	+9.5	dBm
Intercept Point	OIP₃ 2	f _{IFin} 2 = 150.4 MHz	frefout = 1.9 GHz	+6.0	
SSB Noise Figure	SSB NF	freout = 830 MHz, firin = 150 MHz		12.5	dB

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TEST CIRCUIT 1 (fRFout = 830 MHz)

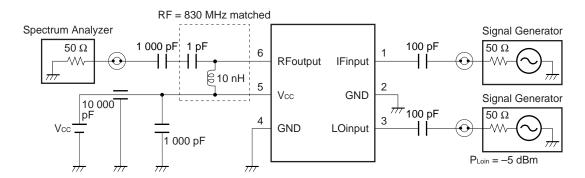
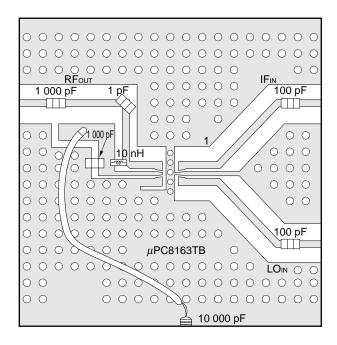


ILLUSTRATION OF TEST CIRCUIT 1 ASSEMBLED ON EVALUATION BOARD



EVALUATION BOARD CHARACTERS

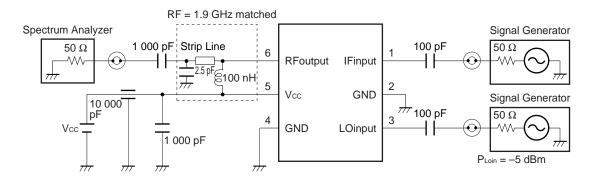
(1) 35 μ m thick double-sided copper clad 35 \times 42 \times 0.4 mm polyimide board

(2) Back side: GND pattern(3) Solder plated patterns(4) ∘O: Through holes

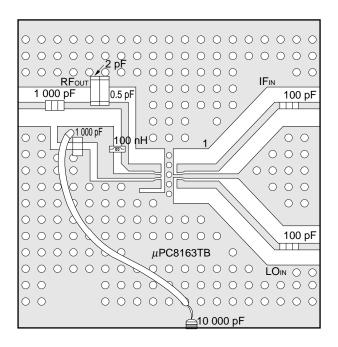
ATTENTION Test circuit or print pattern in this sheet is for testing IC characteristics.

In the case of actual system application, external circuits including print pattern and matching circuit constant of output port should be designed in accordance with IC's S parameters and environmental components.

TEST CIRCUIT 2 (fRFout = 1.9 GHz)



★ ILLUSTRATION OF TEST CIRCUIT 2 ASSEMBLED ON EVALUATION BOARD



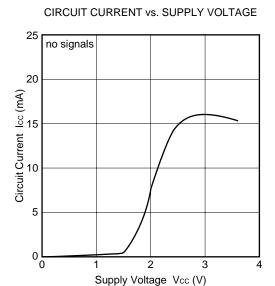
EVALUATION BOARD CHARACTERS

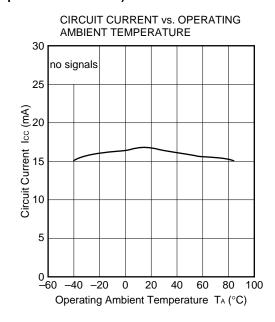
(1) 35 μm thick double-sided copper clad 35 \times 42 \times 0.4 mm polyimide board

(2) Back side: GND pattern(3) Solder plated patterns(4) ∘O: Through holes

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★ TYPICAL CHARACTERISTICS (TA = +25°C, unless otherwise specified Vcc = VRFout)

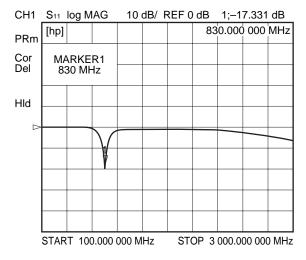




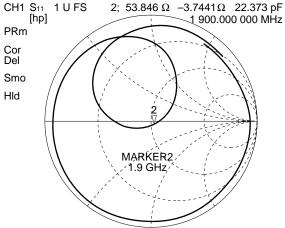
- **★** S-PARAMETER FOR MATCHED RF OUTPUT (Vcc = V_{RFout} = 3.0 V) with TEST CIRCUITS 1 and 2 (monitored at RF connector on board)
 - · RF output matched at 830 MHz

CH1 S₁₁ 1 U FS 1; 53.422 Ω −14.973 Ω 12.807 pF 830.000 000 MHz PRm Cor Del MARKER1 830 MHz

START 100.000 000 MHz STOP 3 000.000 000 MHz

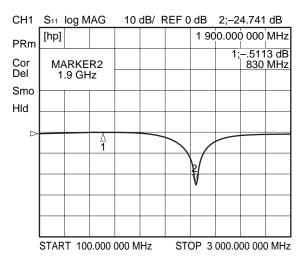


· RF output matched at 1.9 GHz



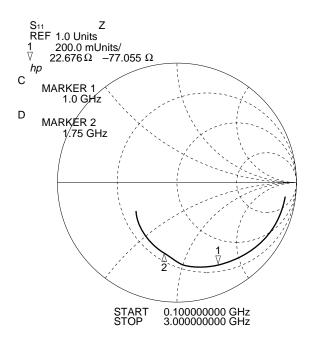
START 100.000 000 MHz

STOP 3 000.000 000 MHz

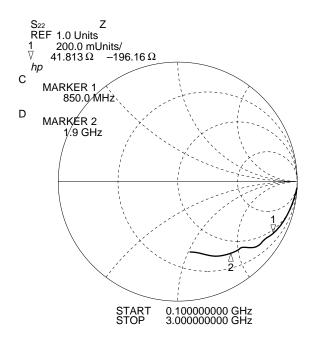


★ S-PARAMETERS FOR EACH PORT (Vcc = VRFout = 3.0 V)

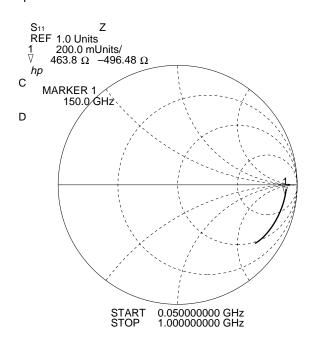
LO port

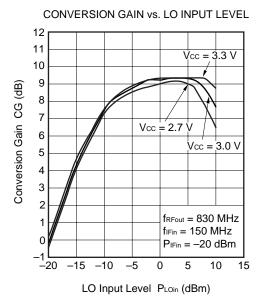


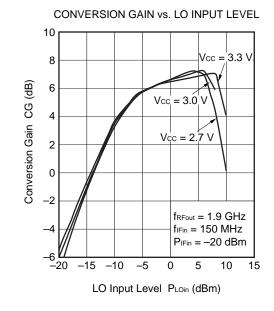
RF port (no matching)

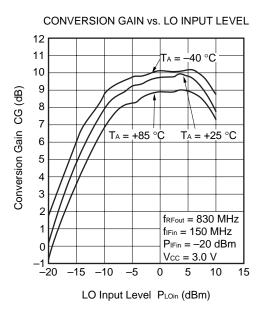


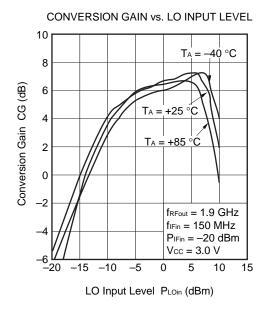
IF port

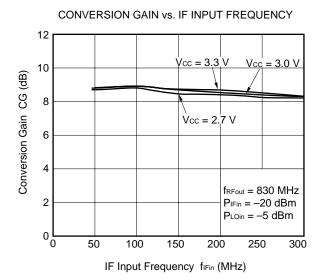


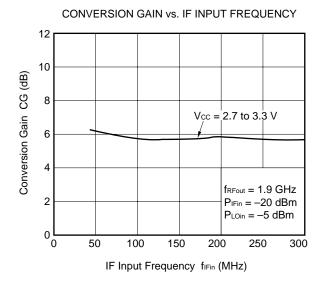


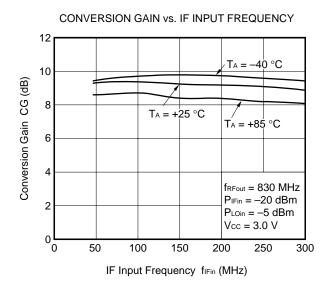


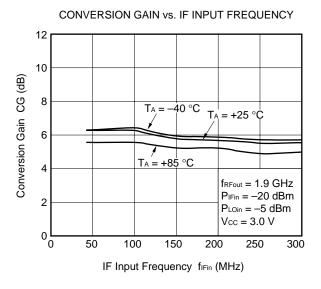


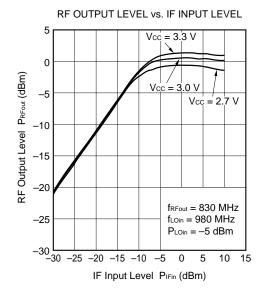


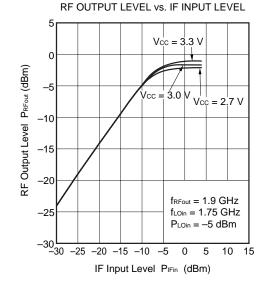


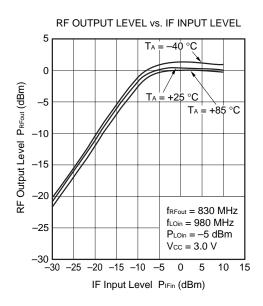


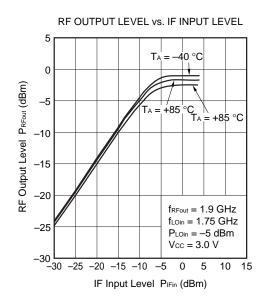


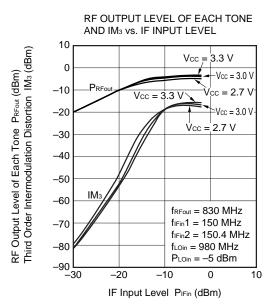


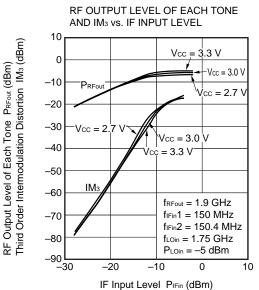




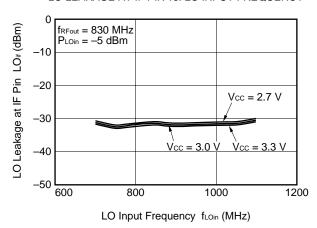




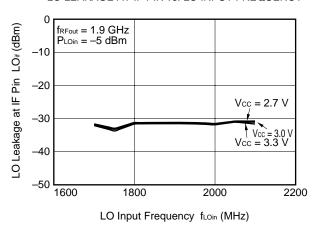




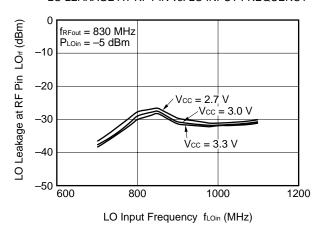
LO LEAKAGE AT IF PIN vs. LO INPUT FREQUENCY



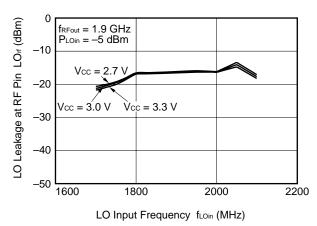
LO LEAKAGE AT IF PIN vs. LO INPUT FREQUENCY



LO LEAKAGE AT RF PIN vs. LO INPUT FREQUENCY

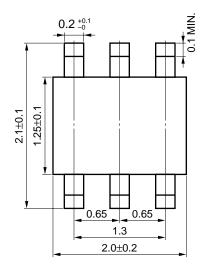


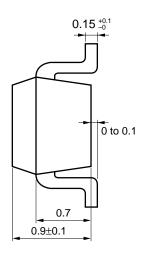
LO LEAKGE AT RF PIN vs. LO INPUT FREQUENCY



PACKAGE DIMENSIONS

6 pin super minimold (Unit: mm)







NOTE ON CORRECT USE

- (1) Observe precautions for handling because of electrostatic sensitive devices.
- (2) Form a ground pattern as wide as possible to keep the minimum ground impedance (to prevent undesired oscillation).
- (3) Keep the track length of the ground pins as short as possible.
- (4) Connect a bypass capacitor (example: 1 000 pF) to the Vcc pin.

RECOMMENDED SOLDERING CONDITIONS

This product should be soldered under the following recommended conditions. For soldering methods and conditions other than those recommended below, contact your NEC sales representative.

Soldering Method	Soldering Conditions	Recommended Condition Symbol
Infrared Reflow	Package peak temperature: 235 °C or below Time: 30 seconds or less (at 210 °C) Count: 3, Exposure limit: None ^{Note}	IR35-00-3
VPS	Package peak temperature: 215 °C or below Time: 40 seconds or less (at 200 °C) Count: 3, Exposure limit: None ^{Note}	VP15-00-3
Wave Soldering	Soldering bath temperature: 260 °C or below Time: 10 seconds or less Count: 1, Exposure limit: None ^{Note}	WS60-00-1
Partial Heating	Pin temperature: 300 °C Time: 3 seconds or less (per side of device) Exposure limit: None ^{Note}	-

Note After opening the dry pack, keep it in a place below 25 °C and 65 % RH for the allowable storage period.

Caution Do not use different soldering methods together (except for partial heating).

For details of recommended soldering conditions for surface mounting, refer to information document SEMICONDUCTOR DEVICE MOUNTING TECHNOLOGY MANUAL (C10535E).

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 - Standard: Computers, office equipment, communications equipment, test and measurement equipment, audio and visual equipment, home electronic appliances, machine tools, personal electronic equipment and industrial robots
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